

Erratum: “Improved electroluminescent efficiency of organic light emitting devices by co-doping N, N’ -Dimethyl-quinacridone and Coumarin6 into tris-(8-hydroxyquinoline) aluminum” [Appl. Phys. Lett.87, 213501 (2005)]

W. M. Su, W. L. Li, Z. R. Hong, M. T. Li, T. Z. Yu, B. Chu, B. Li, Z. Q. Zhang, and Z. Z. Hu

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W. M. Su, W. L. Li,^{a)} Z. R. Hong, M. T. Li, T. Z. Yu, B. Chu, and B. Li

Key Laboratory of Excited State Processes, Changchun Institute of Optics, Fine Mechanics and Physics, Chinese Academy of Sciences, Changchun 130033, People’s Republic of China and Graduate School of Chinese Academy of Sciences, People’s Republic of China

Z. Q. Zhang and Z. Z. Hu

Optic Photo-electronic Materials & Research Development Center, Anshan University of Science and Technology, Anshan 114044, People’s Republic of China

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In the original publication, Appl. Phys. Lett. 87, 213501 (2005), the power efficiencies of devices with respective 1.6% and 0.8% co-dopant indicated in Fig. 3(b) are not con-

sistent with Fig. 3(a) and those specified in the text. The correct label for the curves should be as shown in the Fig. 3(b) reproduced below. By our careless, Fig. 4(b) did not appear in the original article, the corrected figure appears below also:

^{a)}Electronic mail: wllioel@yahoo.com.cn

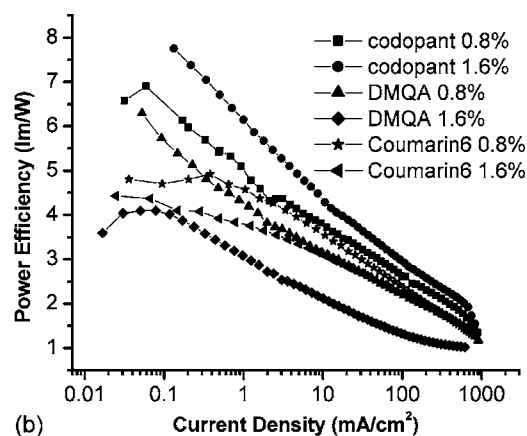


FIG. 3. (b) the power efficiency vs current density characteristics

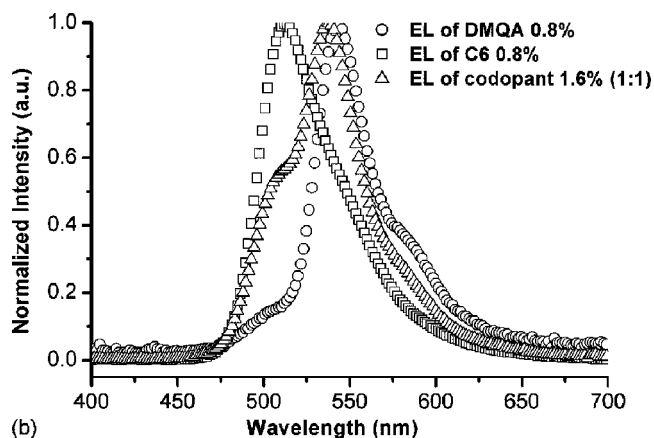


FIG. 4. (b) the EL spectra